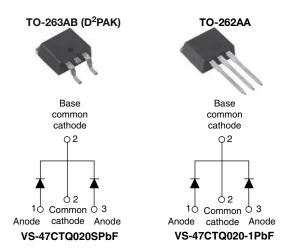


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# High Performance Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY				
I <sub>F(AV)</sub>	2 x 20 A			
$V_{R}$	20 V			
V <sub>F</sub> at I <sub>F</sub>	0.34 V			
I <sub>RM</sub> max.	310 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	18			
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA			
Diode variation	Common cathode			

## **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Center tap configuration
- · Optimized for 3.3 V application
- Ultralow forward voltage drop
- · High frequency operation

 Guard ring for enhanced ruggedness and long term reliability





- term reliabilityHigh purity, high temperature epoxy encapsulation for
- enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

## **DESCRIPTION**

This center tap Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for 3.3 V output power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	40	Α			
V <sub>RRM</sub>		20	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1000	Α			
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.34	V			
T <sub>J</sub>		-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER SYMBOL TEST CONDITIONS VS-47CTQ020SPbF VS-47CTQ020-1PbF UNITS					
Maximum DC reverse voltage	V	125 °C	20	V	
Maximum DC reverse voltage	$V_R$	150 °C	10	V	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg forward current per device		I	I <sub>F(AV)</sub> 50 % duty cycle at T <sub>C</sub> = 135 °C, rectangular waveform —		20	
		IF(AV)			40	
Maximum peak one cycle		I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load	1000 A	
non-repetitive surge currer	non-repetitive surge current per leg		10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	250	
Non-repetitive avalanche e	Non-repetitive avalanche energy per leg		T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 3 mH		18	mJ
Repetitive avalanche curre	ent per leg	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by T <sub>J</sub> maximu		3	Α

Revision: 15-Aug-15 1 Document Number: 94228



# VS-47CTQ020SPbF, VS-47CTQ020-1PbF

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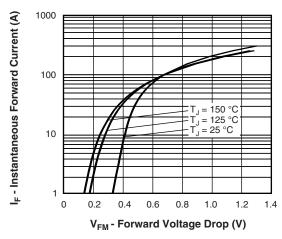
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TES	TEST CONDITIONS		UNITS
		20 A	T 05 °C	0.45	
		40 A	T <sub>J</sub> = 25 °C	0.51	
Maximum forward voltage drop per leg	V (1)	20 A	T 105 %	0.34	.,
	V <sub>FM</sub> <sup>(1)</sup>	40 A	T <sub>J</sub> = 125 °C	0.44	V
		20 A	T 150 °C	0.31	- -
		40 A	T <sub>J</sub> = 150 °C	0.42	
	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = 5 V	60	
			V <sub>R</sub> = 3.3 V	45	
Maximum reverse leakage current per leg		T <sub>J</sub> = 150 °C	V <sub>R</sub> = 10 V	306	mA
current per log		T <sub>J</sub> = 25 °C	V DetectV	3	
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	310	
Threshold voltage	V <sub>F(TO)</sub>	$T_J = T_J$ maximum	<u>.</u>	0.188	V
Forward slope resistance	r <sub>t</sub>			5.9	mΩ
Maximum junction capacitance per leg	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signa	al range 100 kHz to 1 MHz), 25 °C	3000	pF
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lea	d 5 mm from package body	5.5	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

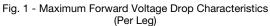
#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHA	THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER		SYMBOL	YMBOL TEST CONDITIONS		UNITS
Maximum junction and stora temperature range	ge	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C
Maximum thermal resistance junction to case per leg	<b>)</b> ,	В	DC operation	1.5	
Maximum thermal resistance, junction to case per package		- R <sub>thJC</sub>	DC operation	0.75	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
Approximate weight				0.07	oz.
Maunting toyour	minimum			6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf · in)
Maybing daying	dovice		Case style TO-263AB (D2PAK)	47CTQ0	208
Marking device			Case style TO-262AA	47CTQ0	20-1

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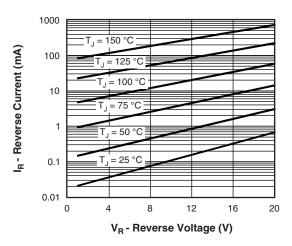


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

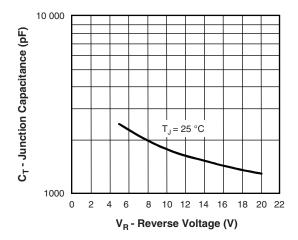


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

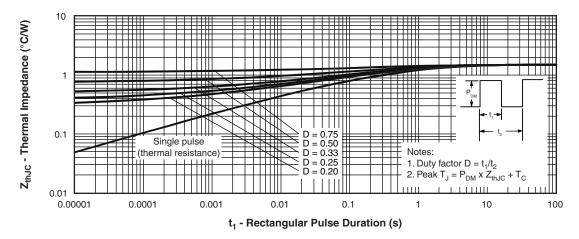


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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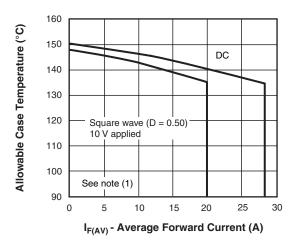


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

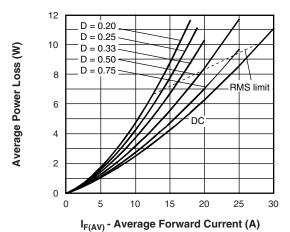


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

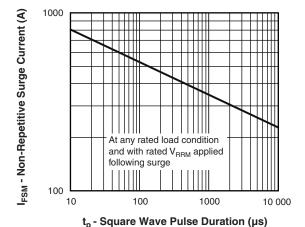


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

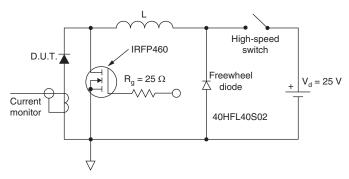


Fig. 8 - Unclamped Inductive Test Circuit

## Note

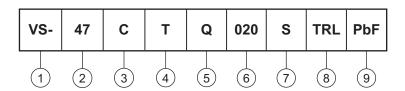
 $^{(1)}$  Formula used:  $T_C = T_J$  - (Pd + Pd\_{REV}) x R<sub>thJC</sub>; Pd = Forward power loss =  $I_{F(AV)}$  x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd\_{REV} = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 10 V

# VS-47CTQ020SPbF, VS-47CTQ020-1PbF

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## **ORDERING INFORMATION TABLE**

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (40 A)
- 3 Circuit configuration: C = common cathode
- **4** T = TO-220
- 5 Schottky "Q" series
  - Voltage rating (020 = 20 V)
- 7 • S = D<sup>2</sup>PAK
  - -1 = TO-262
- 8 • None = tube (50 pieces)
  - TRL = tape and reel (left oriented for D<sup>2</sup>PAK only)
  - TRR = tape and reel (right oriented for D<sup>2</sup>PAK only)
- 9 PbF = lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-42CTQ020SPBF	50	1000	Antistatic plastic tubes		
VS-42CTQ020STRRPBF	800	800	13" diameter plastic tape and reel		
VS-42CTQ020STRLPBF	800	800	13" diameter plastic tape and reel		
VS-42CTQ020-1PBF	50	1000	Antistatic plastic tubes		

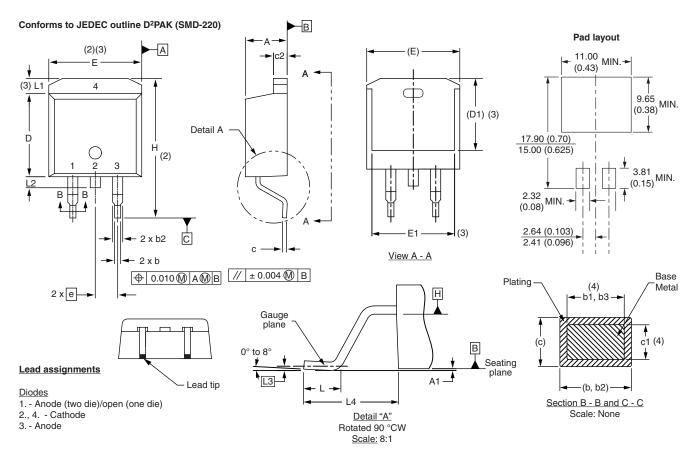
LINKS TO RELATED DOCUMENTS				
Dimensions  TO-263AB (D <sup>2</sup> PAK) <u>www.vishay.com/doc?95046</u>				
Dimensions	TO-262AA	www.vishay.com/doc?95419		
Part marking information		www.vishay.com/doc?95008		
Packaging information		www.vishay.com/doc?95032		



## Vishay Semiconductors

# **D<sup>2</sup>PAK, TO-262**

## **DIMENSIONS - D<sup>2</sup>PAK** in millimeters and inches



	1		1		t .
SYMBOL	MILLIMETERS		INC	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

Document Number: 95014 Revision: 31-Mar-09

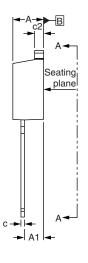
# Vishay Semiconductors

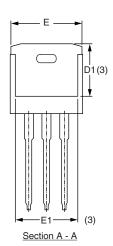
D<sup>2</sup>PAK, TO-262



## **DIMENSIONS - TO-262** in millimeters and inches

# 





**⊕** 0.010 **M** A **M** B

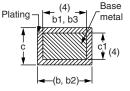
## Lead assignments



#### **Diodes**

1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	MILLIMETERS		INCHES		
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	D BSC		
L	13.46	14.10	0.530	0.555		
L1	=	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

## Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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